



**Product data sheet** 

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NXP Semiconductors



#### **Product specification**

### **PNP** switching transistor

### PZT4403

#### FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

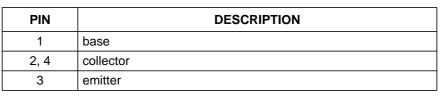
#### APPLICATIONS

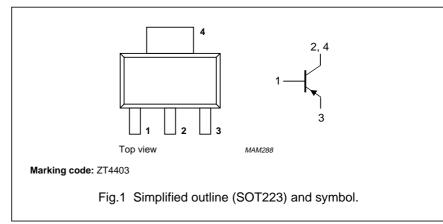
• Switching and linear amplification.

#### DESCRIPTION

PNP switching transistor in a SOT223 plastic package. NPN complement: PZT4401.

#### PINNING





#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current (DC)		-	-600	mA
I <sub>CM</sub>	peak collector current		_	-800	mA
I <sub>BM</sub>	peak base current		_	-200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$ ; note 1	_	1150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	106	K/W
R <sub>th j-s</sub>	thermal resistance from junction to soldering point		25	K/W

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

#### CHARACTERISTICS

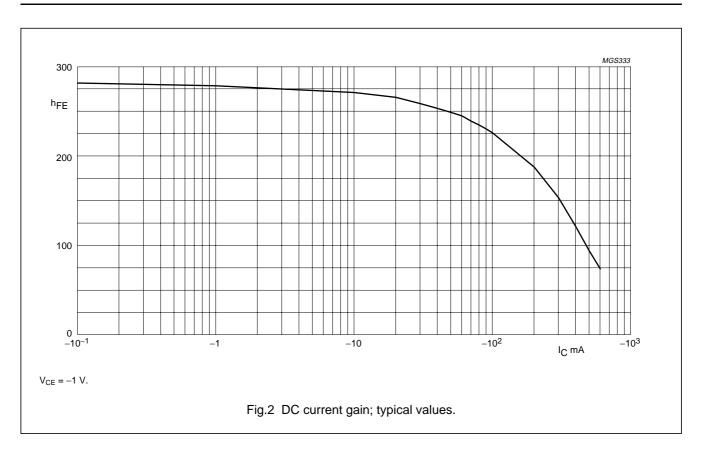
 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

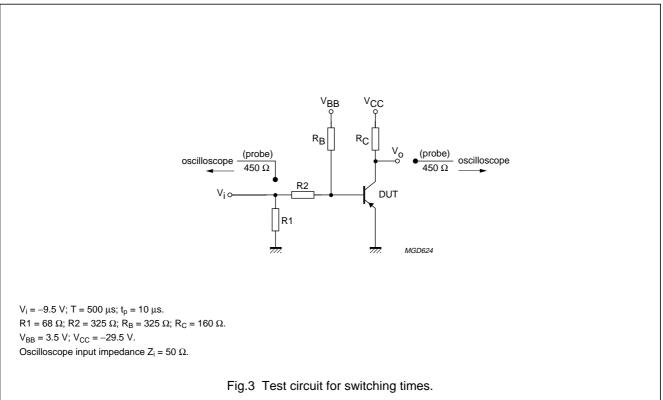
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -40 V$	-	-50	nA
I <sub>EBO</sub>	emitter cut-off current	$I_{C} = 0; V_{EB} = -5 V$	-	-50	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -1$ V; see Fig.2			
		$I_{\rm C} = -0.1  {\rm mA}$	30	-	
		$I_{\rm C} = -1  \rm{mA}$	60	_	
		$I_{\rm C} = -10  {\rm mA}$	100	_	
		I <sub>C</sub> = -150 mA; note 1	100	300	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -500 \text{ mA}; \text{ note } 1$	20	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -150 \text{ mA}; I_{\rm B} = -15 \text{ mA}; \text{ note } 1$	_	-400	mV
		$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}; \text{ note } 1$	_	-750	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{\rm C} = -150 \text{ mA}; I_{\rm B} = -15 \text{ mA}; \text{ note } 1$	_	-950	mV
		$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}; \text{ note } 1$	_	-1300	mV
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0; V_{CB} = -5 V; f = 1 MHz$	_	8.5	pF
C <sub>e</sub>	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = -500 \text{ mV}; f = 1 \text{ MHz}$	_	35	pF
f <sub>T</sub>	transition frequency	$I_{C} = -20 \text{ mA}; V_{CE} = -10 \text{ V};$ f = 100 MHz	200	-	MHz
Switching t	imes (between 10% and 90% lev	els); see Fig.3	•		
t <sub>on</sub>	turn-on time	$I_{Con} = -150 \text{ mA}; I_{Bon} = -15 \text{ mA};$	-	40	ns
t <sub>d</sub>	delay time	$I_{Boff} = 15 \text{ mA}; V_{BB} = 3.5 \text{ V};$	-	15	ns
t <sub>r</sub>	rise time	$V_{CC} = -29.5 V$	-	30	ns
t <sub>off</sub>	turn-off time		_	350	ns
t <sub>s</sub>	storage time	1	-	300	ns
t <sub>f</sub>	fall time	1	_	50	ns

#### Note

1. Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

# PNP switching transistor



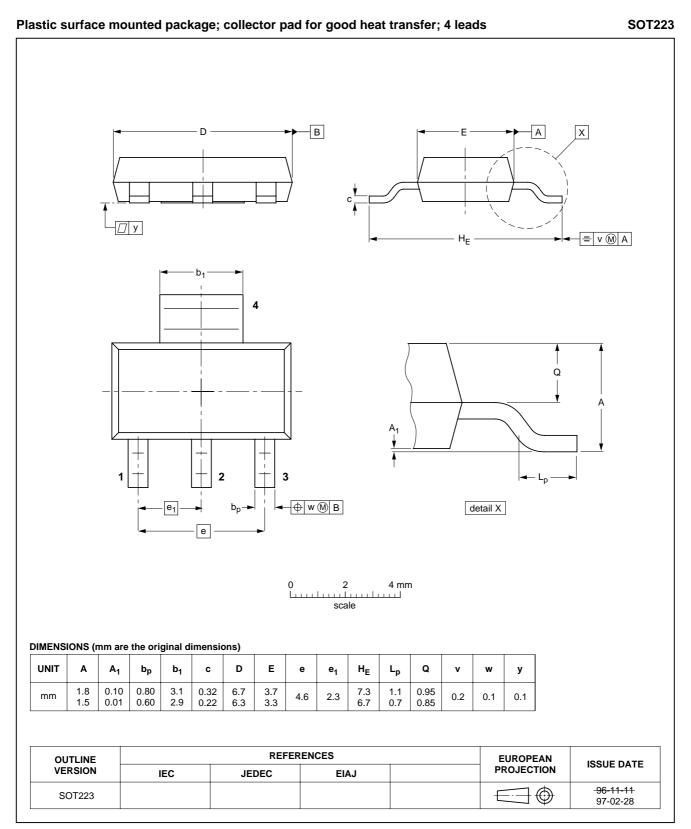


# PZT4403

## PNP switching transistor

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#### PACKAGE OUTLINE



## Legal information

### Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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# **Revision history**

Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PZT4403_N_2	20080117	Product data sheet	-	PZT4403_1	
Modifications: • Page 3 Characteristics table, Switching time conditions; value for I <sub>Bon</sub> and I <sub>Boff</sub> changed					
PZT4403_1 (9397 750 05901)	19990510	Product specification	-	-	

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Date of release: 17 January 2008 Document identifier: PZT4403\_N\_2

